U74CBTLV3125 **CMOS IC**

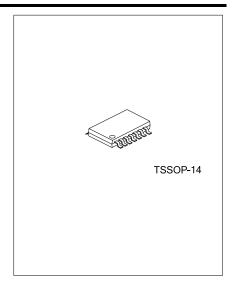
LOW-VOLTAGE QUADRUPLE **FET BUS SWITCH**

DESCRIPTION

The U74CBTLV3125 quadruple FET bus switch features independent line switches. Each switch is disabled when the associated output-enable (\overline{OE}) input is high.

The device is fully specified for partial-power-down applications using Ioff. The Ioff feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

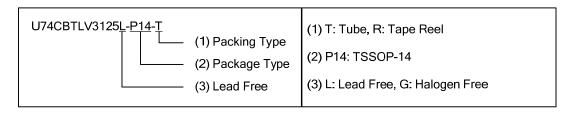


FEATURES

- * 5- Ω Switch Connection Between Two Ports
- * Standard '125-Type Pinout
- * Isolation Under Power-Off Conditions

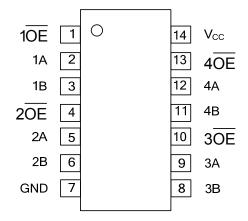
ORDERING INFORMATION

Ordering	Dealtone	Dooking	
Lead Free	Halogen Free	Package	Packing
U74CBTLV3125L-P14-T	U74CBTLV3125G-P14-T	TSSOP-14	Tube
U74CBTLV3125L-P14-R	U74CBTLV3125G-P14-R	TSSOP-14	Tape Reel



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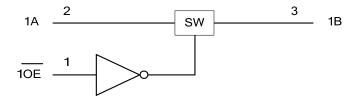
■ PIN CONFIGURATION

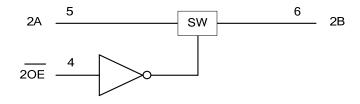


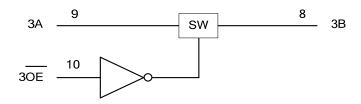
■ FUNCTION TABLE (each bus switch)

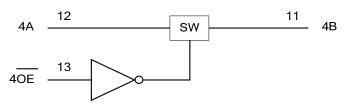
INPUT OE	FUNCTION	
L	A port = B port	
Н	Disconnect	

■ LOGIC DIAGRAM (positive logic)

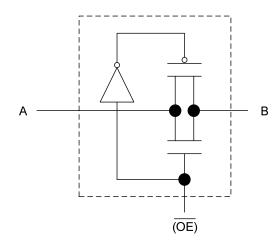








■ **SIMPLIFIED SCHEMATIC**(each FET switch)



■ ABSOLUTE MAXIMUM RATING (unless otherwise specified)(Note 1)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC}	-0.5~4.6	V
Input Voltage	V_{l}	-0.5~4.6	V
Continuous channel current		128	mA
Input Clamp Current(V _{I/O} <0)	I _{IK}	-50	mA
Storage Temperature	T _{STG}	-65 ~ +150	°C

Note 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	113	°C/W

■ RECOMMENDED OPERATING COMDITIONS

PARAMETER	SYMBOL		MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}		2.3		3.6	V
High control imput valtage	\ /	V _{CC} =2.3V~2.7V	1.7			V
High-control input voltage	V _{IH}	V _{CC} =2.7V~3.6V	2			
Laurandralian desidan		V _{CC} =2.3V~2.7V			0.7	V
Low-control input voltage	V_{IL}	V _{CC} =2.7V~3.6V			8.0	\ \
Operating Temperature	T _A		-40		-85	°C

Note: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

■ STATIC CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT					
Digital Input Diode Voltage	V_{IK}	$V_{CC} = 3V$, $I_I = -18mA$					-1.2	V				
Input Leakage Current	I _I	V_{CC} =3.6V, V_{I} = V_{CC} o	r GND				±1	μΑ				
Power off Leakage Carrent	I _{off}	$V_{CC}=0, V_1 \text{ or } V_O=0 \text{ to}$	4.5V				10	μΑ				
Quiosceut Supply Current	I _{CC}	V_{CC} =3.6V, V_{I} = V_{CC}	or GND, I _O =0)			10	μΑ				
Additional Quiescent Supply Control inputs Current	Ι ΛΙ	V _{CC} =3.6V, One inpu Other inputs at V _{CC}	,				300	μА				
Control input Capacitance	Cı	V _O =3V or 0				2.5		рF				
I/O Capacitance (OFF)	C _{IO(OFF)}	V _O =3V or 0, OE=GND			7		рF					
		V 0.0V	\/_O	I _I =64mA		5	8					
		V _{CC} =2.3V	V _I =0	I _I =24mA		5	8					
Desistant between two wants	_	TYP at V _{CC} =2.5V	V _I =1.7V	I _I =-15mA		27	40					
Resistor between two ports	R _{ON}		\/-0\/	I _I =64mA		5	7	Ω				
		V _{CC} =3V	V _{CC} =3V	V _{CC} =3V	V _{CC} =3V	V _{CC} =3V	V _I =0V	I _I =24mA		5	7	
			V _I =2.4V	I _I =-15mA		10	15					

Note: All typical values are at V_{CC} =3.3V, T_A =25°C, unless otherwise noted.

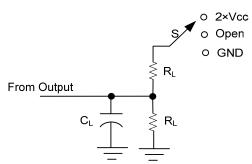
■ DYNAMIC CHARACTERISTICS

See Fig. 1 and Fig. 2 for test circuit and waveforms.

See Fig. 1 and Fig. 2 for lest circuit and waveforms.						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Francisco (A. a. D.) to extent (D. a. A.)	1 /1 /1	V _{CC} =2.5V±0.2V			0.35	
From input (A or B) to output (B or A)	t _{pd} (t _{PLH} /t _{PHL})	V _{CC} =3.3V±0.3V			0.25	ns
From input (OF) to output (A or B)	1 /1 /1	V _{CC} =2.5V±0.2V	2		4.6	
From input (OE) to output (A or B)	t _{en} (t _{PZL} /t _{PZH})	V _{CC} =3.3V±0.3V	2		4.4	
[1 t ₋₁₁₋ (tp. z/tp. z)	V _{CC} =2.5V±0.2V	1.1		3.9	ns
From input (OE) to output (A or B)		V _{CC} =3.3V±0.3V	1.0		4.2	

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

■ TEST CIRCUIT AND WAVEFORMS



V _{CC}	R_L	CL	VΔ
2.5V±0.2V	500	30pF	0.15V
3.3V±0.3V	500	50pF	0.3V

TEST	S
t_{PD}	Open
t _{PHZ} /t _{PZH}	GND
t _{PLZ} /t _{PZL}	2×Vcc

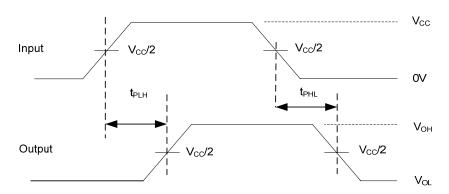
Note: C_L includes probe and jig capacitance.

 t_{PLZ} and t_{PHZ} are the same as $t_{\text{dis}}.$

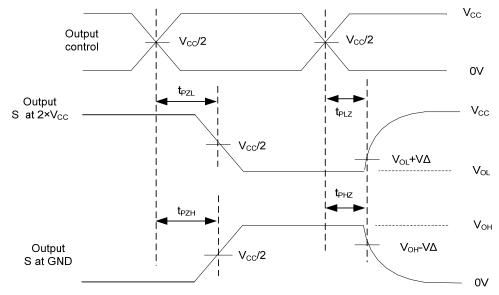
 t_{PZL} and t_{PZH} are the same as $t_{\text{en}}.$

 t_{PLH} and t_{PHL} are the same as t_{PD} .

Fig. 1 Load circuitry for switching times.



PROPAGATION DELAY TIMES



ENABLE AND DISABLE TIMES

Note: All input pulses are supplied by generators having the following characteristics: t_r , $t_f \le 2ns$; PRR $\le 10MHz$; ZO= 50Ω .

Fig. 2 Propagation delay from input(A) to output(B) and Output transition time.



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